

# **BCR4AS-16LH**

Triac Medium Power Use R07DS0331EJ0100 Rev.1.00 Apr 28, 2011

#### **Features**

- $I_{T (RMS)}: 4 A$  $V_{DRM} : 800 V$
- $I_{FGTI}$ ,  $I_{RGTI}$ ,  $I_{RGT\,III}$ : 35 mA or  $10\text{mA}(I_{GT}\text{item:1})$
- High Commutation

- The Product guaranteed maximum junction temperature 150°C
- Non-Insulated Type
- Planar Type

#### **Outline**

RENESAS Package code: PRSS0004ZG-A (Package name : MP-3A)



- 1. T<sub>1</sub> Terminal
- T<sub>2</sub> Terminal
   Gate Terminal
   T<sub>2</sub> Terminal

## **Applications**

Switching mode power supply, small motor control, heater control, and other general purpose AC power control applications

## **Maximum Ratings**

Parameter	Symbol	Voltage class 16	Unit
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	800	V
Non-repetitive peak off-state voltage Note1	$V_{DSM}$	960	V

Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T (RMS)</sub>	4	А	Commercial frequency, sine full wave 360°conduction, Tc = 129°C Note3
Surge on-state current	I <sub>TSM</sub>	30	А	60 Hz sinewave 1 full cycle, peak value, non-repetitive
I <sup>2</sup> t for fusion	l <sup>2</sup> t	3.7	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60 Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	3	W	
Average gate power dissipation	P <sub>G (AV)</sub>	0.3	W	
Peak gate voltage	$V_{GM}$	10	V	
Peak gate current	I <sub>GM</sub>	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass	_	0.32	g	Typical value

## **Electrical Characteristics**

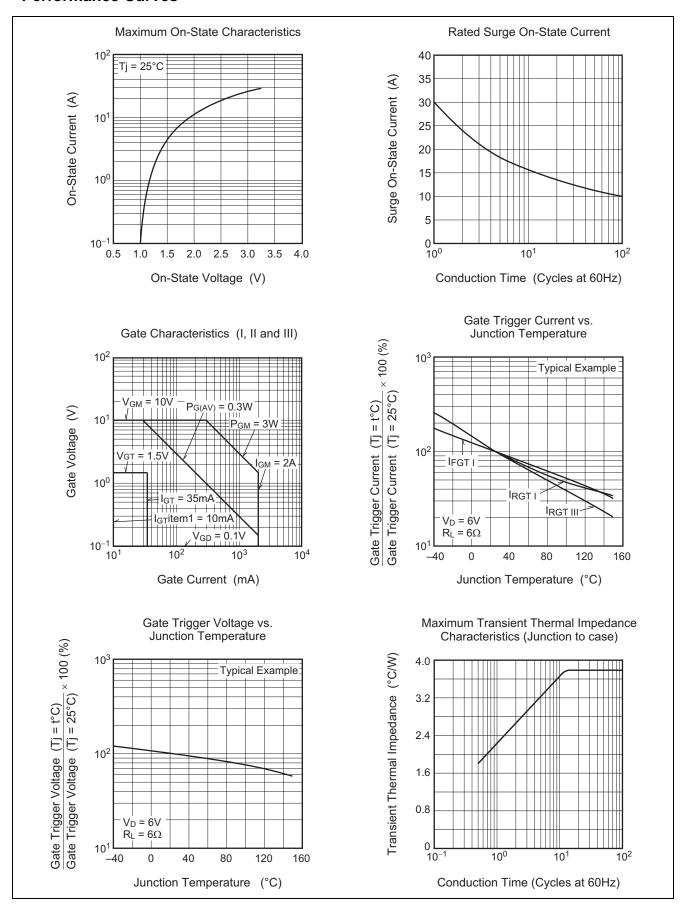
Parameter		Symbol	BCR4AS-16LH-1			BCR4AS-16LH		Unit	Test conditions	
		Syllibol	(I <sub>GT</sub> item : 1)						rest conditions	
			Min.	Тур.	Max.	Min.	Тур.	Max.		
Repetitive peak off-state cu	urrent	I <sub>DRM</sub>			2.0		_	2.0	mA	Tj = 150°C
										V <sub>DRM</sub> applied
On-state voltage		V <sub>TM</sub>	_	_	1.6	_	_	1.6	V	Tc = 25°C, I <sub>TM</sub> = 6 A instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{FGTI}$	_	-	1.5	_	_	1.5	V	$Tj = 25^{\circ}C, V_D = 6 V$
	II	$V_{RGTI}$			1.5			1.5	V	$R_L = 6 \Omega$ , $R_G = 330 \Omega$
	III	$V_{RGTIII}$	_		1.5		—	1.5	V	
Gate trigger curent <sup>Note2</sup>	I	$I_{FGTI}$	_		10		—	35	mA	$Tj = 25^{\circ}C, V_D = 6 V$
	II	$I_{RGT_{\mathrm{I}}}$	_		10		—	35	mA	$R_L = 6 \Omega$ , $R_G = 330 \Omega$
	III	$I_{RGT_{III}}$			10		_	35	mA	
Gate non-trigger voltage		$V_{GD}$	0.2	_	_	0.2	_	_	V	Tj = 125°C
										$V_D = 1/2 V_{DRM}$
			0.1	_	_	0.1	_	_	V	Tj = 150°C
										$V_D = 1/2 V_{DRM}$
Thermal resistance		R <sub>th (j-c)</sub>	_	-	3.8	_	_	3.8	°C/W	Junction to case <sup>Note3</sup>
Critical-rate of decay of on-	state	(di/dt)c	2.5	_	_	_			A/ms	Tj = 125°C
commutating current Note4										(dv/dt)c < 10 V/μs
			_	_	_	3.0		_	A/ms	Tj = 125°C
										(dv/dt)c < 100 V/μs

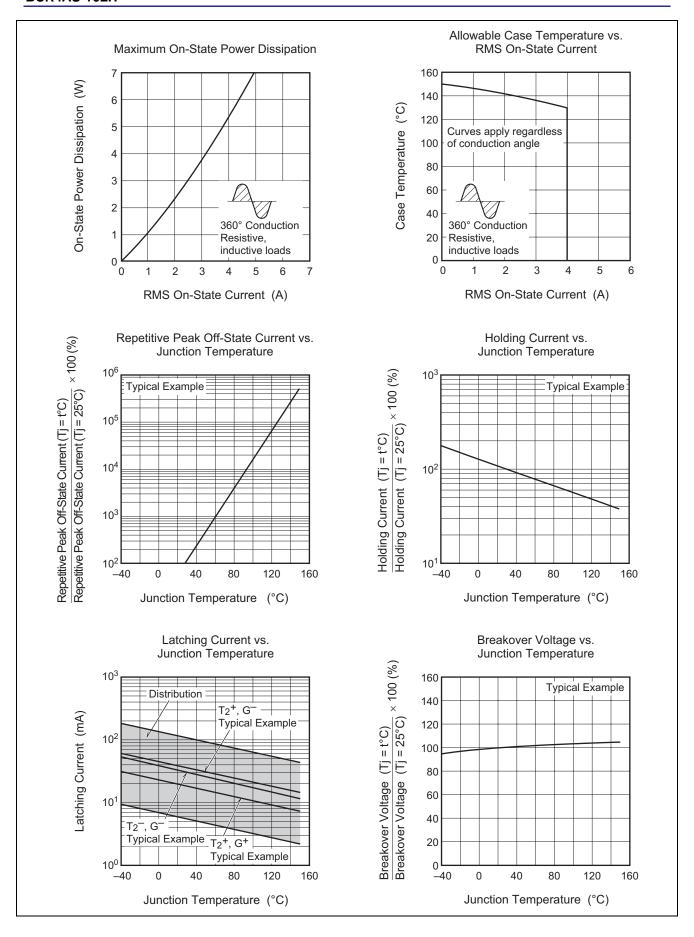
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

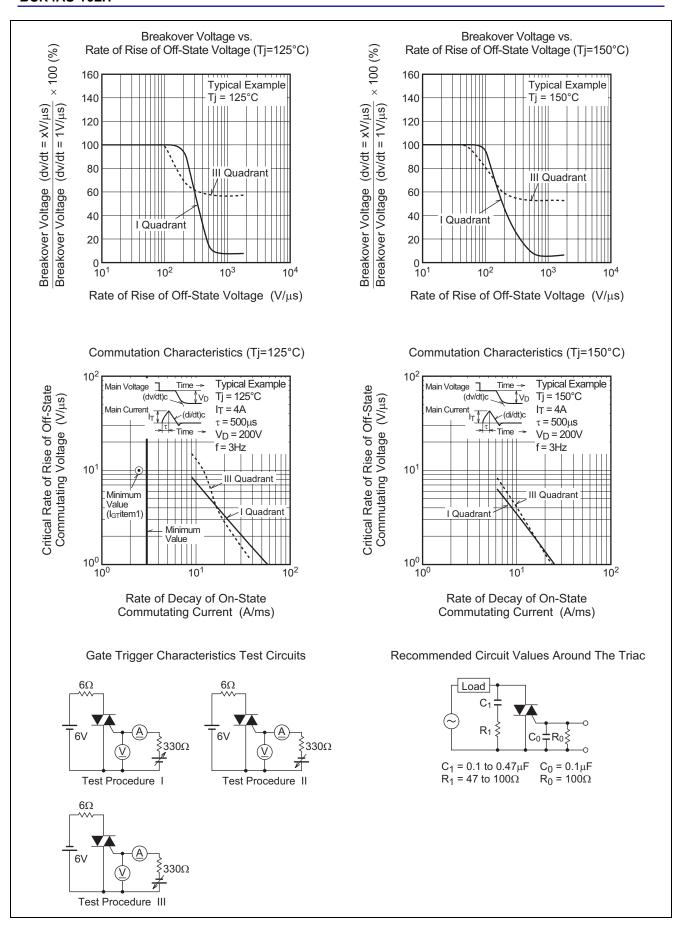
- 3. Case temperature is measured on the  $T_2 \, \text{tab}$ .
- 4. Test conditions of the critical-rate of decay of on-state commutating current is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)				
1. Junction temperature Tj = 125°C	Supply Voltage  → Time				
2. Peak off-state voltage V <sub>D</sub> = 400 V	Main Current (di/dt)c  Time				
2. Rate of rise of off-state commutating voltage (dv/dt)c < 10 V/μs (I <sub>GT</sub> item : 1) (dv/dt)c < 100 V/μs	Main Voltage Time (dv/dt)c				

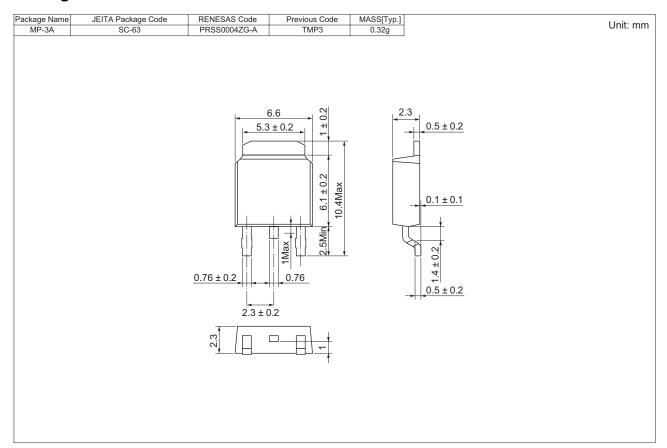
#### **Performance Curves**







## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Packing	Quantity	Remark
BCR4AS-16LH#B00	Tube	75 pcs.	
BCR4AS-16LH-1#B00	Tube	75 pcs.	IGT item1
BCR4AS-16LH-T13#B00	Embossed Tape	3000 pcs.	Taping direction "T1"
BCR4AS-16LH-1T13#B00	Embossed Tape	3000 pcs.	Taping direction "T1", IGT item1

Note: Please confirm the specification about the shipping in detail.

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enesas Electronics America Inc. 80 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. d: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Boume End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-2035-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No. 1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-5887-7589

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852-2886-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiv Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
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